





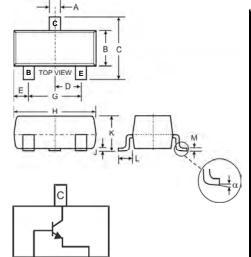
#### NPN SURFACE MOUNT VHF/UHF TRANSISTOR

### **Features**

- Designed for VHF/UHF Amplifier Applications and High Output VHF Oscillators
- High Current Gain Bandwidth Product
- Ideal for Mixer and RF Amplifier Applications with collector currents in the 100µA - 30 mA Range
- Lead, Halogen and Antimony Free, RoHS Compliant "Green" Device (Notes 3 and 4)

## **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Information: See Page 3 Ordering Information: See Page 3
- Weight: 0.008 grams (approximate)



| SOT-23               |       |                      |  |  |  |  |  |  |  |  |
|----------------------|-------|----------------------|--|--|--|--|--|--|--|--|
| Dim                  | Min   | Max                  |  |  |  |  |  |  |  |  |
| Α                    | 0.37  | 0.51                 |  |  |  |  |  |  |  |  |
| В                    | 1.20  | 1.40                 |  |  |  |  |  |  |  |  |
| C                    | 2.30  | 2.50                 |  |  |  |  |  |  |  |  |
| D                    | 0.89  | 1.03                 |  |  |  |  |  |  |  |  |
| E                    | 0.45  | 0.60<br>2.05<br>3.00 |  |  |  |  |  |  |  |  |
| G                    | 1.78  |                      |  |  |  |  |  |  |  |  |
| Н                    | 2.80  |                      |  |  |  |  |  |  |  |  |
| J                    | 0.013 | 0.10                 |  |  |  |  |  |  |  |  |
| K                    | 0.903 | 1.10                 |  |  |  |  |  |  |  |  |
| L                    | 0.45  | 0.61                 |  |  |  |  |  |  |  |  |
| М                    | 0.085 | 0.180                |  |  |  |  |  |  |  |  |
| α                    | 0°    | 8°                   |  |  |  |  |  |  |  |  |
| All Dimensions in mm |       |                      |  |  |  |  |  |  |  |  |

# **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic                                   | Symbol                            | Value       | Unit |  |  |
|--|-----------------------------------|-------------|------|--|--|
| Collector-Base Voltage                           | V <sub>CBO</sub>                  | 40          | V    |  |  |
| Collector-Emitter Voltage                        | V <sub>CEO</sub>                  | 40          | V    |  |  |
| Emitter-Base Voltage                             | V <sub>EBO</sub>                  | 4.0         | V    |  |  |
| Collector Current - Continuous (Note 1)          | Ic                                | 50          | mA   |  |  |
| Power Dissipation (Note 1)                       | P <sub>d</sub>                    | 300         | mW   |  |  |
| Thermal Resistance, Junction to Ambient (Note 1) | $R_{	heta JA}$                    | 417         | °C/W |  |  |
| Operating and Storage Temperature Range          | T <sub>i</sub> , T <sub>STG</sub> | -55 to +150 | °C   |  |  |

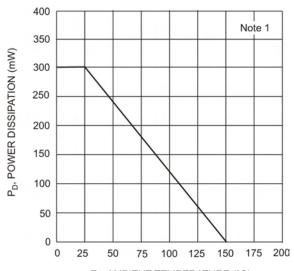
# Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic                       | Symbol                | Min | Max  | Unit | Test Condition   |  |  |  |  |  |
|--------------------------------------|-----------------------|-----|------|------|--|--|--|--|--|--|
| OFF CHARACTERISTICS (Note 2)         |                       |     |      |      |  |  |  |  |  |  |
| Collector-Emitter Breakdown Voltage  | V <sub>(BR)CEO</sub>  | 40  | _    | V    | $I_{C} = 1 \text{mA}, I_{B} = 0$                         |  |  |  |  |  |
| Collector-Base Breakdown Voltage     | V <sub>(BR)CBO</sub>  |     | _    | V    | $I_C = 100 \mu A, I_E = 0$                               |  |  |  |  |  |
| Emitter-Base Breakdown Voltage       | V <sub>(BR)EBO</sub>  | 4.0 | _    | V    | $I_E = 10\mu A, I_C = 0$                                 |  |  |  |  |  |
| Collector Cutoff Current             | I <sub>CBO</sub>      |     | 100  | nA   | $V_{CB} = 30V, I_E = 0$                                  |  |  |  |  |  |
| Emitter Cutoff Current               | I <sub>EBO</sub>      |     | 100  | nA   | $V_{EB} = 2V, I_{C} = 0$                                 |  |  |  |  |  |
| ON CHARACTERISTICS (Note 2)          |                       |     |      |      |  |  |  |  |  |  |
| DC Current Gain                      | h <sub>FE</sub>       | 30  | _    | _    | $I_C = 8mA, V_{CE} = 10.0V$                              |  |  |  |  |  |
| Collector-Emitter Saturation Voltage | V <sub>CE</sub> (SAT) |     | 0.5  | V    | $I_C = 4mA$ , $I_B = 400 \mu A$                          |  |  |  |  |  |
| Base-Emitter On Voltage              | V <sub>BE(SAT)</sub>  |     | 0.95 | V    | $I_C = 4mA, V_{CE} = 10.0V$                              |  |  |  |  |  |
| SMALL SIGNAL CHARACTERISTICS         |                       |     |      |      |  |  |  |  |  |  |
| Current Gain-Bandwidth Product       | f <sub>T</sub>        | 400 | _    | MHz  | V <sub>CE</sub> = 10V, f = 100MHz, I <sub>C</sub> = 8mA  |  |  |  |  |  |
| Collector-Base Capacitance           | C <sub>CB</sub>       |     | 0.7  | pF   | $V_{CB} = 10V$ , $f = 1.0MHz$ , $I_E = 0$                |  |  |  |  |  |
| Collector-Base Feedback Capacitance  | $C_RB$                |     | 0.65 | pF   | $V_{CB} = 10V$ , $f = 1.0MHz$ , $I_E = 0$                |  |  |  |  |  |
| Collector-Base Time Constant         | Rb'Cc                 | _   | 9    | ps   | I <sub>C</sub> = 4mA, V <sub>CB</sub> = 10V, f = 31.8MHz |  |  |  |  |  |

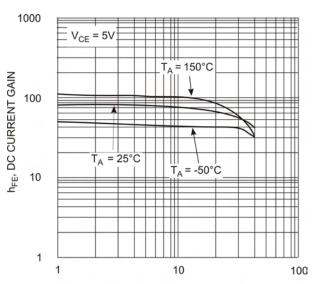
Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch pad layout, as shown on Diodes Inc. suggested pad layout Notes: document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

- Short duration pulse test used to minimize self-heating effect.
- No purposefully added lead. Halogen and Antimony Free.
  Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb<sub>2</sub>O<sub>3</sub> Fire Retardants.

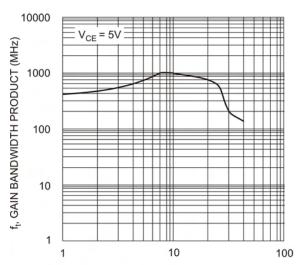




T<sub>A</sub>, AMBIENT TEMPERATURE (°C) Fig. 1, Max Power Dissipation vs Ambient Temperature



I<sub>C</sub>, COLLECTOR CURRENT (mA) Fig. 3, DC Current Gain vs. Collector Current



I<sub>C</sub>, COLLECTOR CURRENT (mA)
Fig. 5, Gain Bandwidth Product vs Collector Current

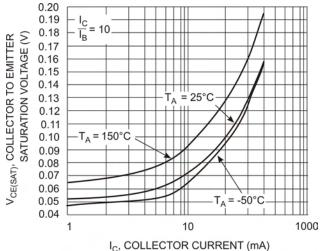


Fig. 2 Collector Emitter Saturation Voltage
vs. Collector Current

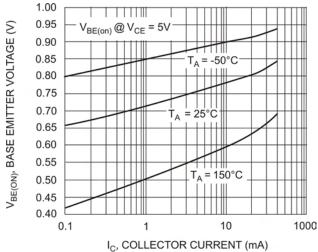


Fig. 4 Base Emitter Voltage vs. Collector Current

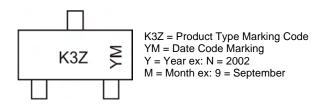


### **Ordering Information** (Note 5)

| Device      | Packaging | Shipping         |  |  |  |  |
|-------------|-----------|------------------|--|--|--|--|
| MMBTH24-7-F | SOT-23    | 3000/Tape & Reel |  |  |  |  |

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



Date Code Key

| Date Code | INEY |      |      |      |      |      |      |      |      |      |      |      |      |      |      |
|-----------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|
| Year      | 1998 | 1999 | 2000 | 2001 | 2002 | 2003 | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 | 2010 | 2011 | 2012 |
| Code      | J    | K    | L    | М    | N    | Р    | R    | S    | Т    | U    | V    | W    | Х    | Υ    | Z    |
| Month     | Jan  | Fe   | b    | Mar  | Apr  | May  | Ju   | n    | Jul  | Aug  | Sep  | Oc   | t I  | Nov  | Dec  |
| Code      | 1    | 2    |      | 3    | 4    | 5    | 6    |      | 7    | 8    | 9    | 0    |      | N    | D    |

### IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

### LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.